

PDTA114ET

50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

19 February 2024

Product data sheet

1. General description

PNP Resistor-Equipped Transistor (RET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTC114ET

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

3. Applications

- · Digital application in automotive and industrial segments
- Cost-saving alternative for BC847 series in digital applications
- Controlling IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	1	input (base)]3	
2	GND	ground (emitter)		R1
3	0	output (collector)	SOT23	R2 GND sym003

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PDTA114ET	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23		

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PDTA114ET	803

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

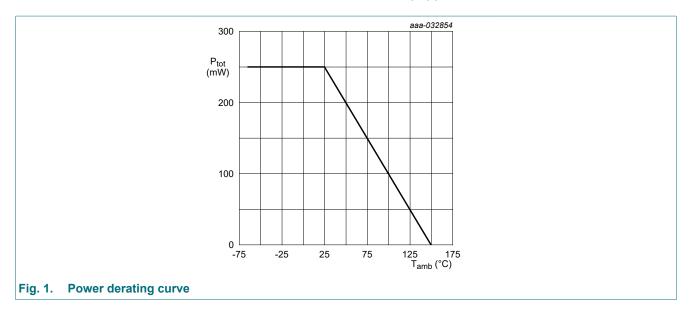
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V_{CEO}	collector-emitter voltage	open base		-	-50	V
V_{EBO}	emitter-base voltage	open collector		-	-10	V
VI	input voltage			-40	10	V
Io	output current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

 $^{[1] \}quad \text{Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, } 35~\mu\text{m copper, tin-plated and standard footprint.}$

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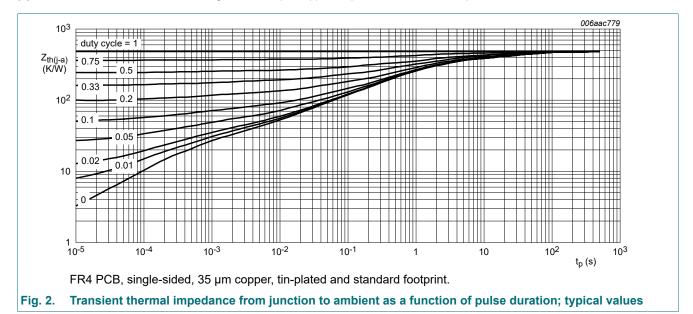


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.



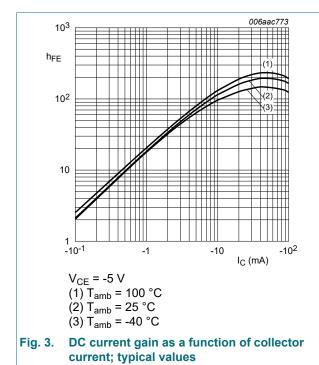
50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω

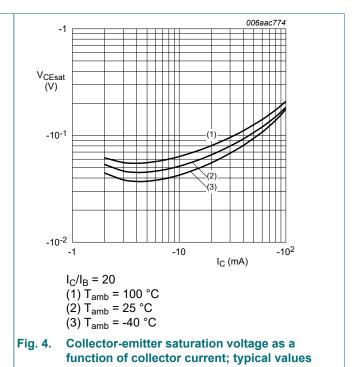
10. Characteristics

Table 7. Characteristics

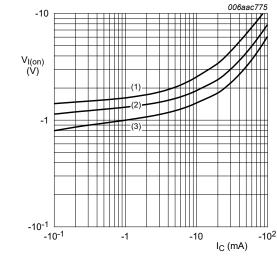
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A; T _{amb} = 25 °C		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	-1	μΑ
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-400	μA
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -5 mA; T _{amb} = 25 °C		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	-150	mV
$V_{I(off)}$	off-state input voltage	V_{CE} = -5 V; I_{C} = -100 μ A; T_{amb} = 25 °C		-	-1.1	-0.8	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I_{C} = -10 mA; T_{amb} = 25 °C		-2.5	-1.8	-	V
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	8.0	1	1.2	
C _c	collector capacitance	/ _{CB} = -10 V; I _E = 0 A; i _e = 0 A; = 1 MHz; T _{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	180	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor.



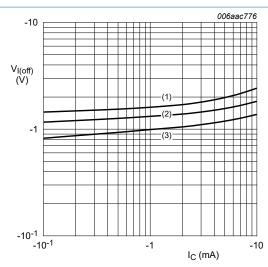


50 V, 100 mA PNP resistor-equipped transistor; R1 = 10 k Ω , R2 = 10 k Ω



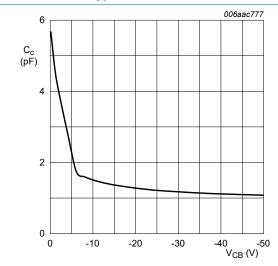
V_{CE} = -0.3 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Fig. 5. On-state input voltage as a function of collector | Fig. 6. current; typical values



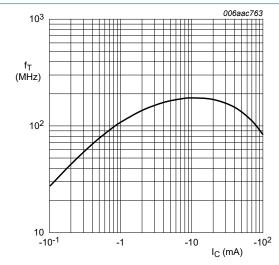
V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Off-state input voltage as a function of collector current; typical values



 $f = 1 MHz; T_{amb} = 25 °C$ Fig. 7. Collector capacitance as a function of collector-

base voltage; typical values



Transition frequency as a function of collector Fig. 8. current; typical values of built-in transistor

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11. Test information

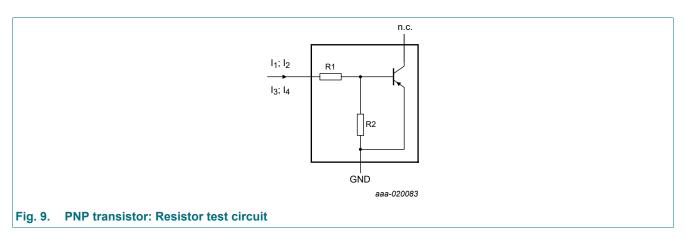
Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

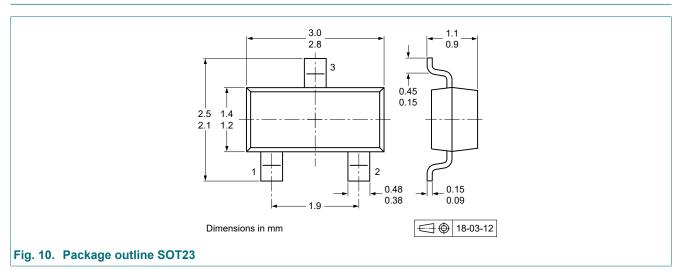


Resistor test conditions

Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	l ₂	l ₃	14
PDTA114ET	10	10	-350 μΑ	-450 μA	350 μΑ	450 µA

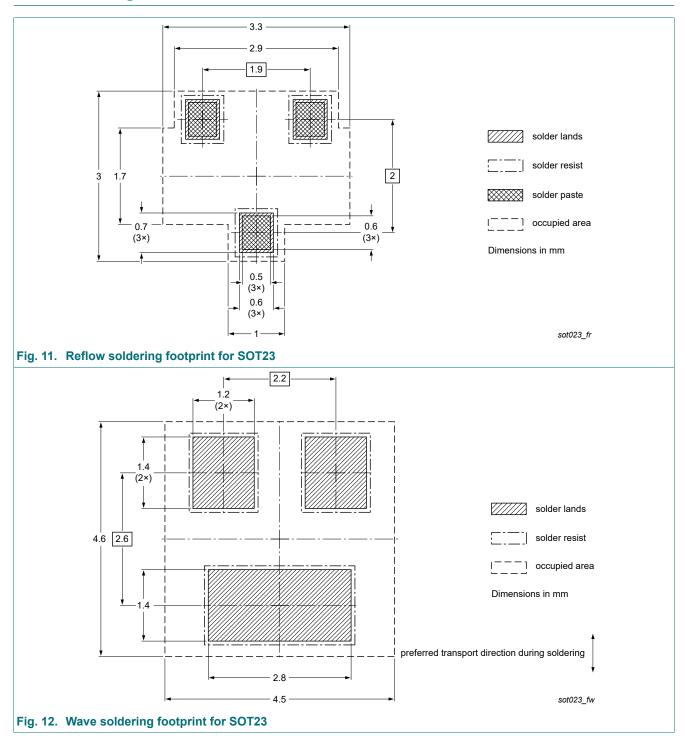
12. Package outline



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13. Soldering



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14. Revision history

Table 9. Revision history

Table 3. Revision mistory				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PDTA114ET v.13	20240219	Product data sheet	-	PDTA114E_SER v.12
Modification:	Pinning: Gra	phic symbol adjusted		
PDTA114ET v.12	20230401	Product data sheet	-	PDTA114E_SER v.11
PDTA114ET v.11	20230207	Product data sheet	-	PDTA114E_SER v.10
PDTA114E_SER v.10	20111221	Product data sheet	-	PDTA114E_SER v.9
PDTA114E_SER v.9	20111122	Product data sheet	-	PDTA114E_SERIES v.8
PDTA114E_SERIES v.8	20040802	Product specification	-	PDTA114E_SERIES v.7
PDTA114E_SERIES v.7	20030410	Product specification	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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